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# Switch-mode Power Rectifier

60 V, 20 A

# MBR20L60CTG MBRF20L60CTG

#### Features and Benefits

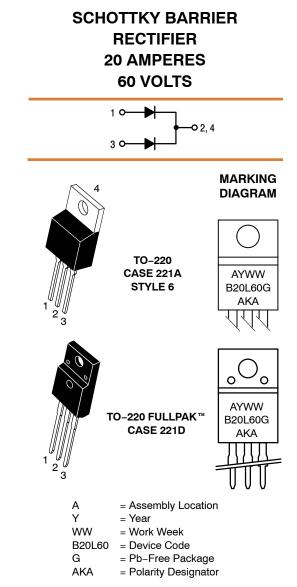
- Low Power Loss/High Efficiency
- High Surge Capacity
- 20 A Total (10 A Per Diode Leg)
- Guard-Ring for Stress Protection
- These Devices are Pb-Free and are RoHS Compliant\*

#### Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

#### Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 Units Per Plastic Tube
- \*For additional information on our Pb–Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



#### **ORDERING INFORMATION**

Device	Package	Shipping
MBR20L60CTG	TO-220 (Pb-Free)	50 Units / Rail
MBRF20L60CTG	TO-220FP (Pb-Free)	50 Units / Rail

#### MAXIMUM RATINGS (Per Diode Leg)

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	60	V	
Average Rectified Forward CurrentMBR20L60CT (Rated $V_R$ ) $T_C = 138^{\circ}C$ Per DiodeMBRF20L60CT (Rated $V_R$ ) $T_C = 123^{\circ}C$ Per Device	I <sub>F(AV)</sub>	10 20	A	
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	240	A	
Operating Junction Temperature (Note 1)	TJ	-55 to +150	°C	
Storage Temperature	T <sub>stg</sub>	-65 to +175	°C	
ESD Ratings: Machine Model = C Human Body Model = 3B		> 400 > 8000	V	
Maximum Repetitive Peak Avalanche Voltage ( $t_p < 1 \ \mu s, T_J < 150^{\circ}$ C, I <sub>AR</sub> < 51 A)	V <sub>ARM</sub>	85	V	
Maximum Single-Pulse Peak Avalanche Voltage ( $t_p < 1 \ \mu s, T_J < 150^{\circ}$ C, I <sub>AR</sub> < 51 A)	V <sub>ASM</sub>	85	V	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

#### **THERMAL CHARACTERISTICS**

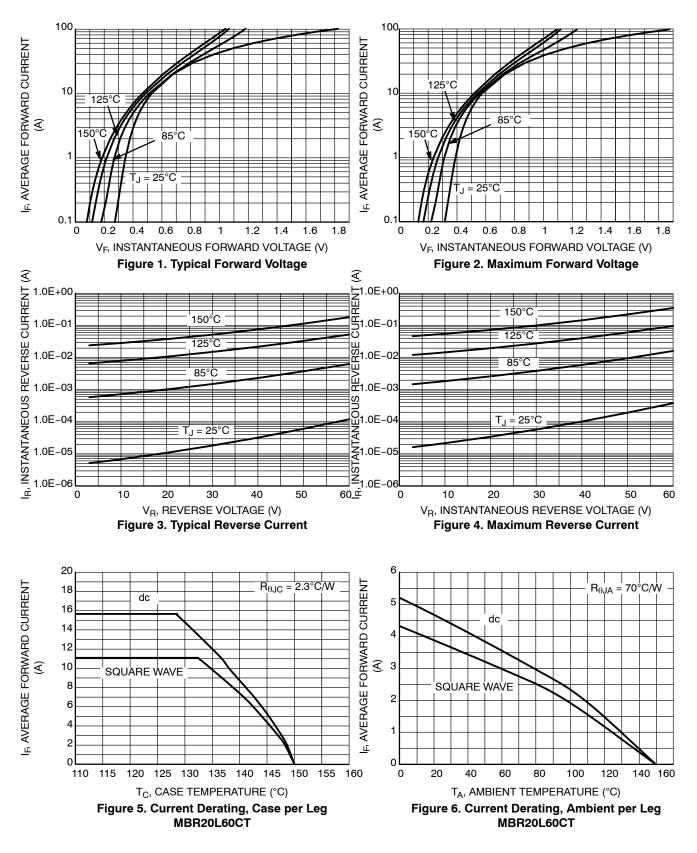
Charact	eristic	Symbol	Value	Unit
Maximum Thermal Resistance				°C/W
MBR20L60CTG	<ul> <li>Junction-to-Case</li> </ul>	$R_{\theta JC}$	2.3	
	<ul> <li>Junction-to-Ambient</li> </ul>	$R_{\theta JA}$	70	
MBRF20L60CTG	<ul> <li>Junction-to-Case</li> </ul>	$R_{\theta JC}$	5.2	
	<ul> <li>Junction-to-Ambient</li> </ul>	$R_{\theta JA}$	75	

#### ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Characteristic	Symbol	Тур	Max	Unit
	VF	0.53 0.49 0.68 0.64	0.57 0.54 0.73 0.69	V
Maximum Instantaneous Reverse Current (Note 2) (Rated DC Voltage, $T_C = 25^{\circ}C$ ) (Rated DC Voltage, $T_C = 125^{\circ}C$ )	İR	118 52	380 96	μA mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤[2.0%.



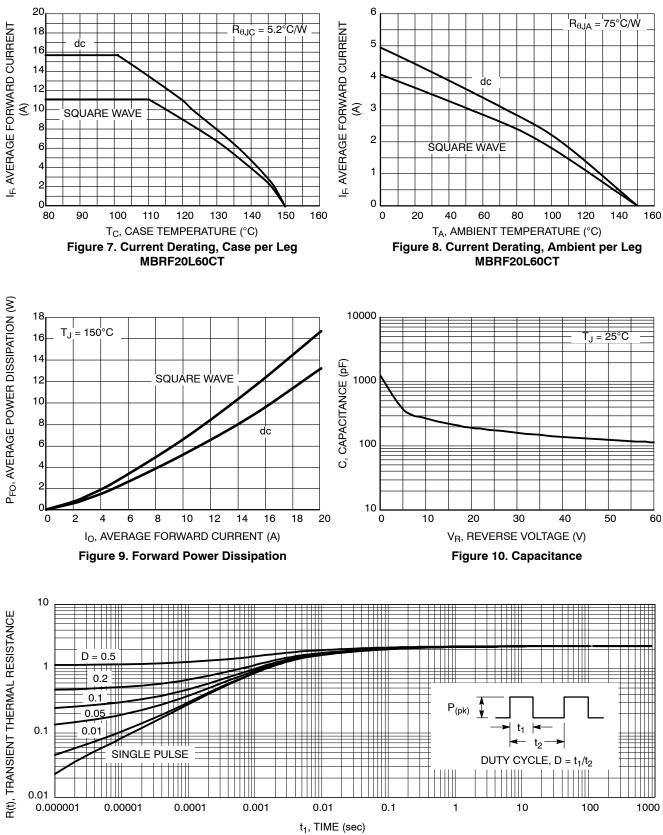
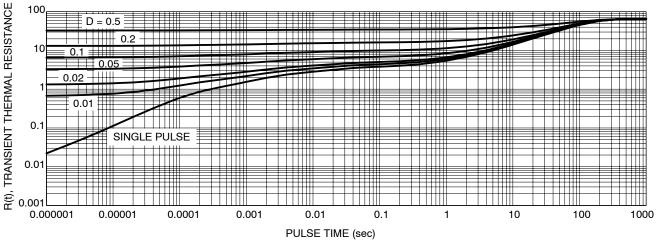
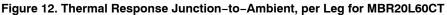


Figure 11. Thermal Response Junction-to-Case, per Leg for MBR20L60CT





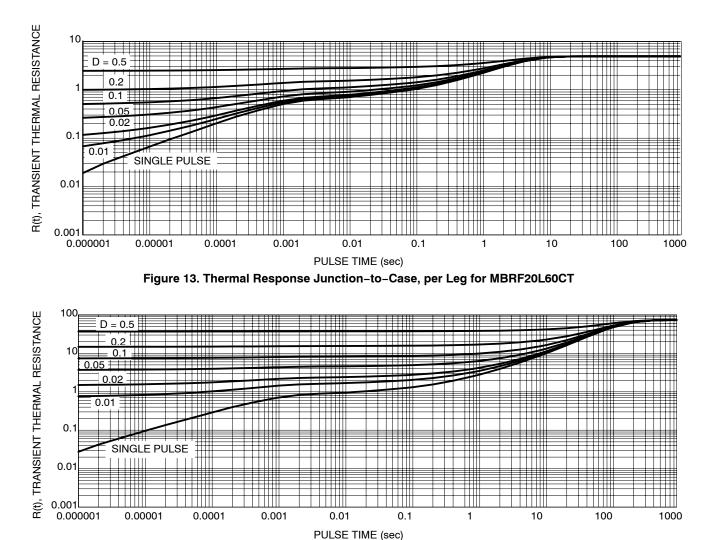


Figure 14. Thermal Response Junction-to-Ambient, per Leg for MBRF20L60CT

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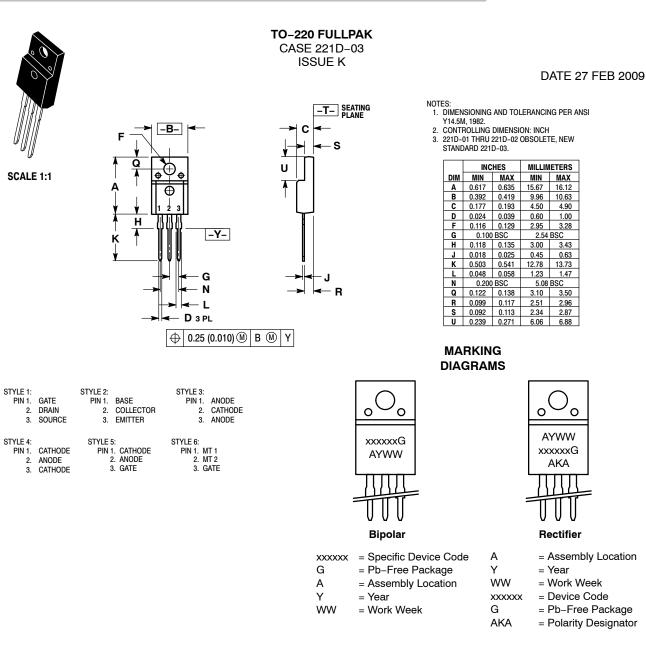
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			4. N	лах м	VIDTHFOR	F102 DEV	ICE = 1.35MM		
			Г		INC	HES	MILLIM	ETERS	
				ым 🛛	MIN.	MAX.	MIN.	MAX.	
	2 3			A	0.570	0.620	14.48	15.75	
				в	0.380	0.415	9.66	10.53	
н —	₩₩			с	0.160	0.190	4.07	4.83	
	7 \7	H I		D	0.025	0.038	0.64	0.96	
z_				F	0.142	0.161	3.60	4.09	
<u> </u>	I K			G	0.095	0.105	2.42	2.66	
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· · · ·	- <b>→  </b> D			Q	0.100	0.120	2.54	3.04	
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2. 3. 4. STYLE 5: PIN 1. 2.	BASE         PIN 1.           COLLECTOR         2.           EMITTER         3.           COLLECTOR         4.           STYLE 6:         GATE           DRAIN         2.	EMITTER COLLECTOR EMITTER ANODE CATHODE	IN 1. CAT 2. ANO 3. GAT 4. ANO LE 7: IN 1. CAT 2. ANO	ode Te ode Thode ode		2. 3. 4. STYLE 8: PIN 1. 2.	MAIN TERMINAL MAIN TERMINAL GATE MAIN TERMINAL CATHODE ANODE	2	
4. STYLE 9: PIN 1.	DRAIN 4. STYLE 10 GATE PIN 1.	ANODE CATHODE GATE P SOURCE	3. CAT 4. ANO LE 11: IN 1. DR/ 2. SOU	ode Ain		4. STYLE 12: PIN 1.	EXTERNAL TRIP ANODE MAIN TERMINAL MAIN TERMINAL	. 1	
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